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### Vishay General Semiconductor

# **Dual Common Cathode Schottky Rectifier**



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 30 A					
V <sub>RRM</sub>	35 V, 45 V, 60 V					
I <sub>FSM</sub>	350 A					
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.50 V, 0.56 V					
T <sub>J</sub> max.	150 °C					
Package	TO-3P (TO-247AD)					
Circuit configurations	Common cathode					

#### **FEATURES**

- Power pack
- Guardring for overvoltage protection
- Low power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max.10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-3P (TO-247AD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	M6035P	M6045P	M6060P	UNIT		
Maximum repetitive peak reverse voltage		$V_{RRM}$	35	45	60	V	
Maximum average forward rectified current at (fig.1)	total device	-	60			А	
	per diode	I <sub>F(AV)</sub>	30				
Peak forward surge current 8.3 ms single half sine-wave on rated load per diode	I <sub>FSM</sub>	350			Α		
Peak repetitive reverse current at $t_p = 2 \mu s$ , 1 kHz per diode		I <sub>RRM</sub>	2.0			Α	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +150			°C	

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# M6035P, M6045P, M6060P

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	CVMDOL	TEST CONDITIONS		M6035P	M6045P	M6060P		UNIT
PARAMETER	SYMBOL			TYP.	MAX.	TYP.	MAX.	
Instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>J</sub> = 25 °C	0.42	-	0.43	-	V
		I <sub>F</sub> = 20 A		0.49	-	0.52	-	
		$I_F = 30 \text{ A}$		0.54	0.60	0.59	0.64	
		I <sub>F</sub> = 10 A	T <sub>J</sub> = 125 °C	0.31	-	0.33	-	
		I <sub>F</sub> = 20 A		0.42	-	0.47	-	
		$I_F = 30 \text{ A}$		0.50	0.55	0.56	0.60	
Reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	V <sub>R</sub>	T <sub>J</sub> = 25 °C	135	600	240	600	μA
			T <sub>J</sub> = 125 °C	110	160	140	160	mA
Typical junction capacitance	CJ	4.0 V, 1 MI	Нz	1150	-	1090	-	pF

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	M6035P	M6035P M6045P M6060P			
Typical thermal resistance per diode	$R_{\theta JC}$	2.0			°C/W	

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
M6045P-E3/45	6.14	45	30/tube	Tube				
M6060P-E3/45	6.14	45	30/tube	Tube				

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25 \, ^{\circ}\text{C}$ unless otherwise noted)

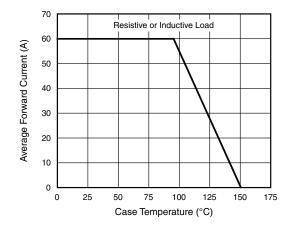


Fig. 1 - Forward Current Derating Curve

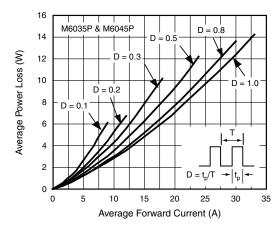


Fig. 2 - Forward Power Loss Characteristics Per Diode

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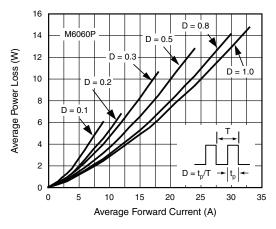
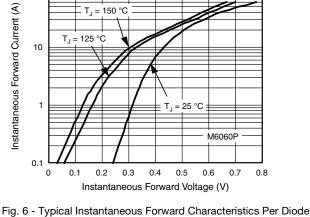


Fig. 3 - Forward Power Loss Characteristics Per Diode



100

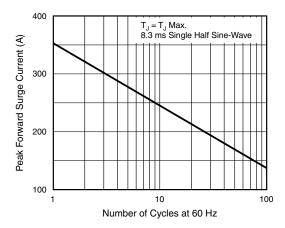


Fig. 4 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

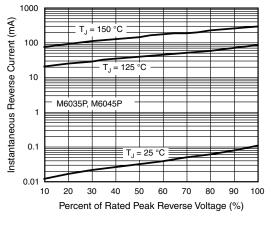


Fig. 7 - Typical Reverse Characteristics Per Diode

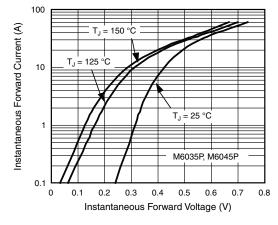


Fig. 5 - Typical Instantaneous Forward Characteristics Per Diode

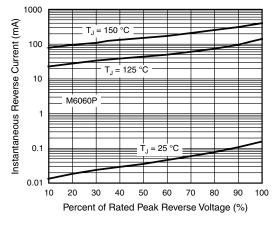


Fig. 8 - Typical Reverse Characteristics Per Diode





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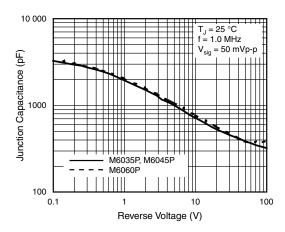


Fig. 9 - Typical Junction Capacitance Per Diode

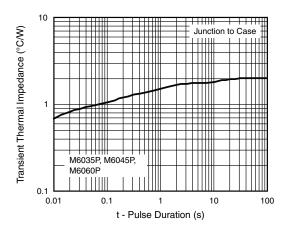
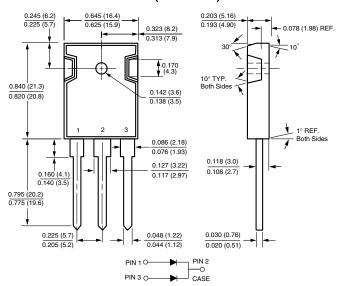


Fig. 10 - Typical Transient Thermal Impedance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### TO-3P (TO-247AD)



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